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FAIRCHILD SEMICONDUCTOR®

November 2013

FDP65N06

N-Channel UniFET™ MOSFET

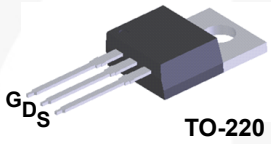
60 V, 65 A, 16 mΩ

Features

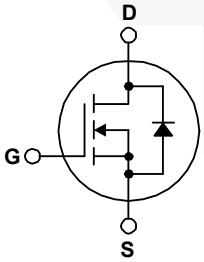
- $R_{DS(on)}$ = 13 mΩ (Typ.) @ V_{GS} = 10 V, I_D = 32.5 A
- Low Gate Charge (typical 33 nC)
- Low Crss (typical 35 pF)
- Fast Switching
- Improved dv/dt Capability

Description

UniFET™ MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



TO-220



Absolute Maximum Ratings

T_C = 25°C unless otherwise noted.

Symbol	Parameter		FDP65N06	Units
V_{DSS}	Drain-Source Voltage		60	V
I_D	Drain Current - Continuous (T_C = 25°C)		65	A
	Drain Current - Continuous (T_C = 100°C)		41	A
I_{DM}	Drain Current - Pulsed	(Note 1)	260	A
V_{GSS}	Gate-Source Voltage		± 20	V
E_{AS}	Single Pulsed Avalanche Energy	(Note 2)	430	mJ
I_{AR}	Avalanche Current	(Note 1)	65	A
E_{AR}	Repetitive Avalanche Energy	(Note 1)	13.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.5	V/ns
P_D	Power Dissipation (T_C = 25°C)		135	W
	- Derate above 25°C		1.08	W/°C
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C

Thermal Characteristics

Symbol	Parameter	FDP65N06	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.92	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP65N06	FDP65N06	TO-220	Tube	N/A	50 units

Electrical Characteristics

T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_D = 250 μA	60	-	-	V
ΔBV_{DSS} / ΔT_J	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C	-	0.5	-	V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 60 V, V_{GS} = 0 V	-	-	1	μA
		V_{DS} = 48 V, T_C = 125°C	-	-	10	μA
I_{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = 20 V, V_{DS} = 0 V	-	-	100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = -20 V, V_{DS} = 0 V	-	-	-100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250 μA	2.0	-	4.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	V_{GS} = 10 V, I_D = 32.5 A	-	0.013	0.016	Ω
g_{FS}	Forward Transconductance	V_{DS} = 40 V, I_D = 32.5 A	-	39	-	S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 25 V, V_{GS} = 0 V, f = 1.0 MHz	-	1670	2170	pF
C_{oss}	Output Capacitance		-	464	600	pF
C_{rss}	Reverse Transfer Capacitance		-	35	52	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 30 V, I_D = 65A, R_G = 25 Ω (Note 4)	-	24	58	ns
t_r	Turn-On Rise Time		-	94	200	ns
$t_{d(off)}$	Turn-Off Delay Time		-	98	210	ns
t_f	Turn-Off Fall Time		-	52	114	ns
Q_g	Total Gate Charge	V_{DS} = 48 V, I_D = 65A, V_{GS} = 10 V (Note 4)	-	33	43	nC
Q_{gs}	Gate-Source Charge		-	10	-	nC
Q_{gd}	Gate-Drain Charge		-	11	-	nC
Drain-Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain-Source Diode Forward Current		-	-	65	A
I_{SM}	Maximum Pulsed Drain-Source Diode Forward Current		-	-	260	A
V_{SD}	Drain-Source Diode Forward Voltage	V_{GS} = 0 V, I_S = 65 A	-	-	1.4	V
t_{rr}	Reverse Recovery Time	V_{GS} = 0 V, I_S = 65 A, dI_F / dt = 100 A/μs	-	62	-	ns
Q_{rr}	Reverse Recovery Charge		-	132	-	nC

NOTES:

1. Repetitive Rating : Pulse width limited by maximum junction temperature.
2. L = 47 μH, I_{AS} = 65 A, V_{DD} = 50 V, R_G = 25 Ω, Starting T_J = 25°C.
3. I_{SD} ≤ 65 A, di/dt ≤ 200 A/μs, V_{DD} ≤ BV_{DSS}, Starting T_J = 25°C.
4. Essentially independent of operating temperature.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

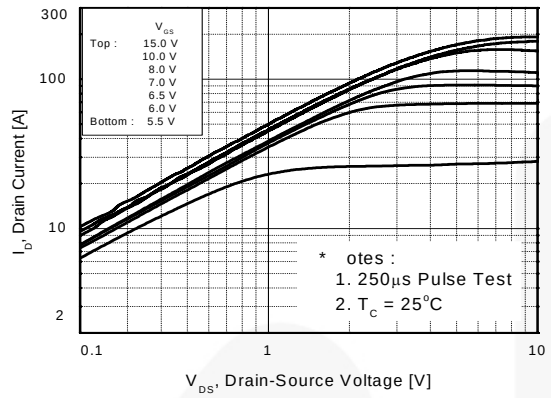


Figure 2. Transfer Characteristics

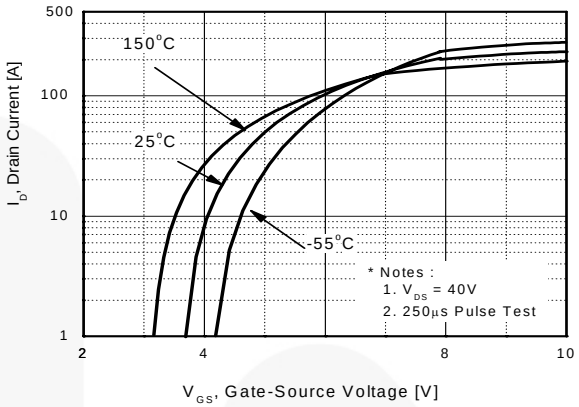


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

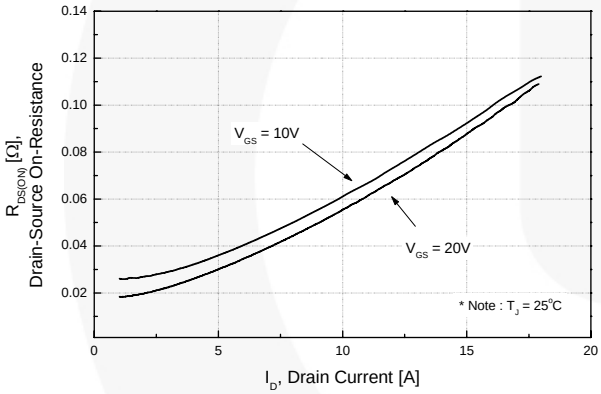


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue

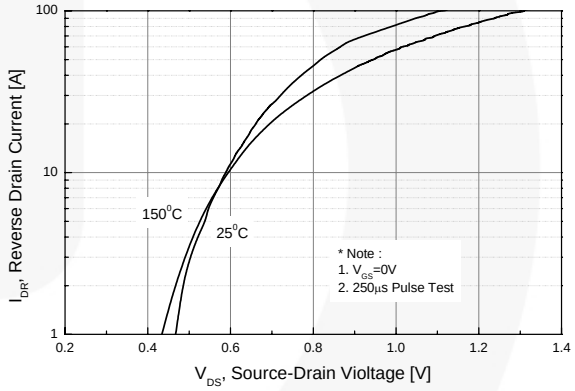


Figure 5. Capacitance Characteristics

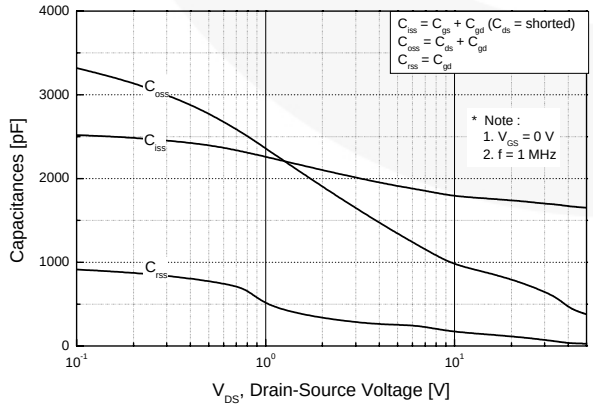
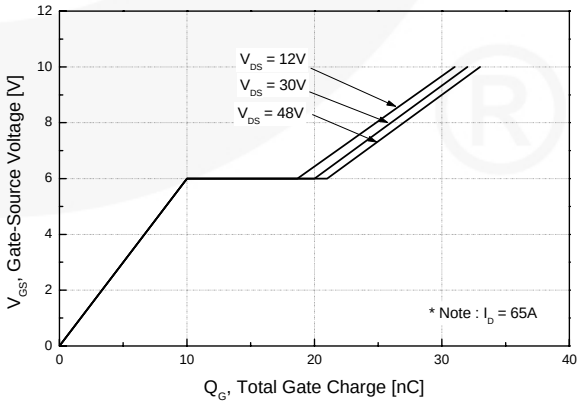


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

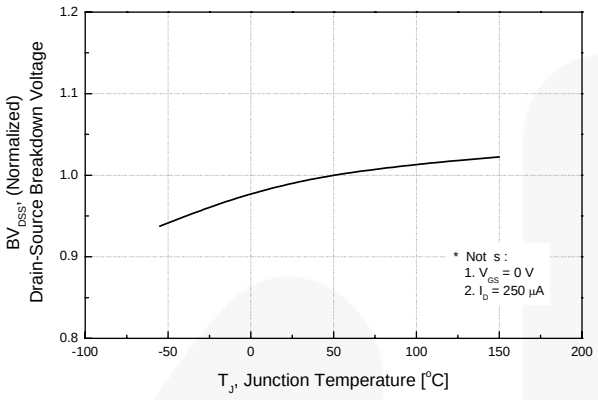


Figure 8. On-Resistance Variation vs. Temperature

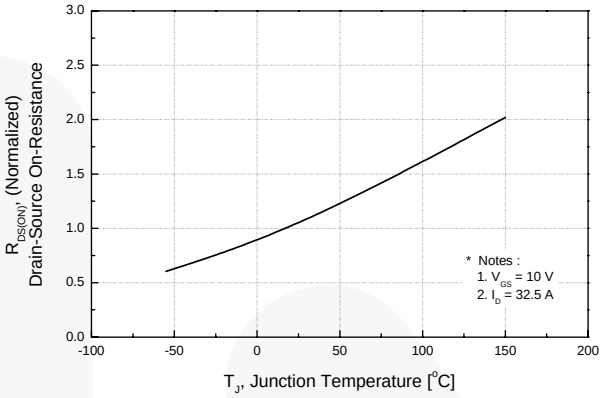


Figure 9. Maximum Safe Operating Area

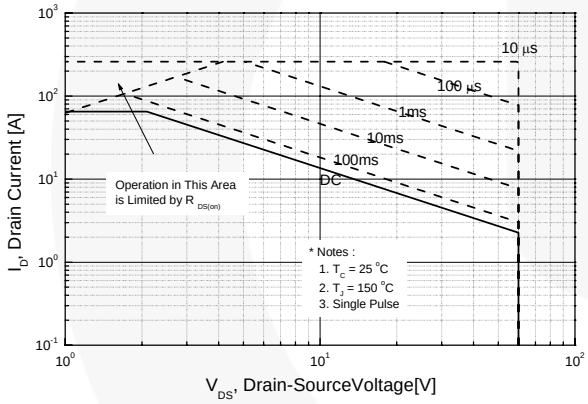


Figure 10. Maximum Drain Current vs. Case Temperature

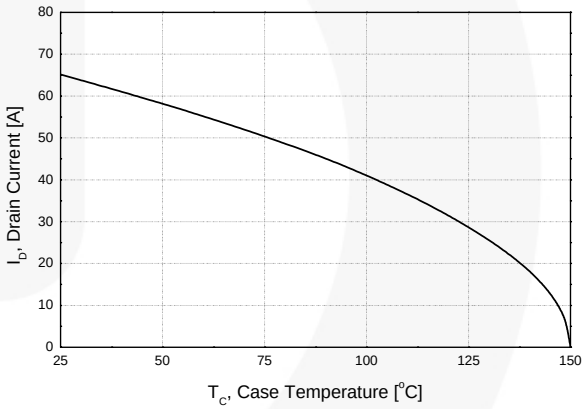


Figure 11. Transient Thermal Response Curve

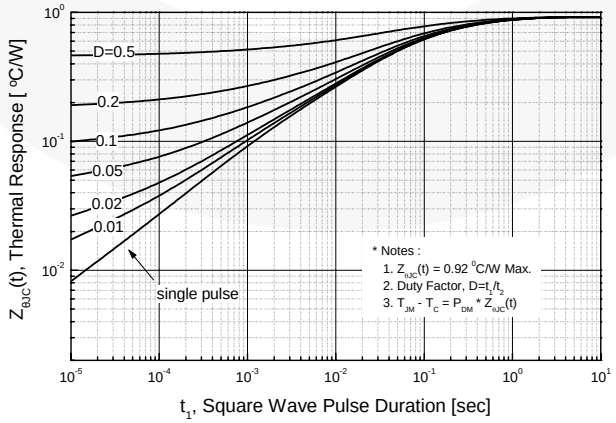


Figure 12. Gate Charge Test Circuit & Waveform

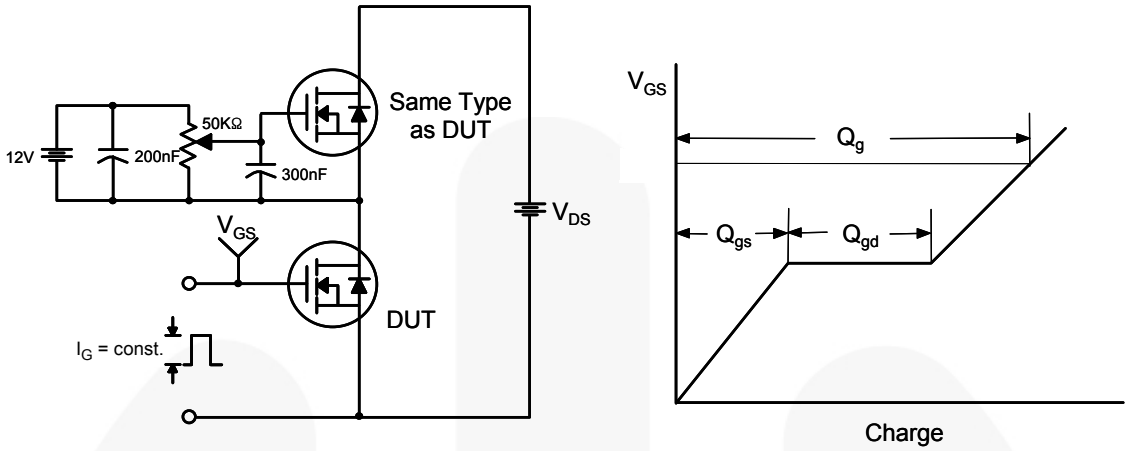


Figure 13. Resistive Switching Test Circuit & Waveforms

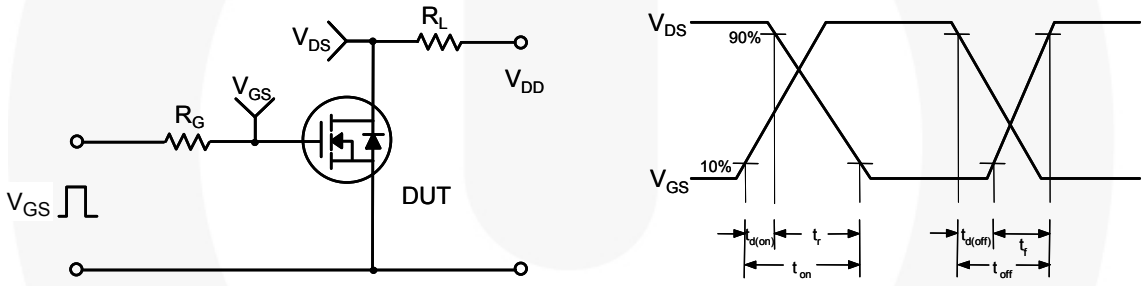


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

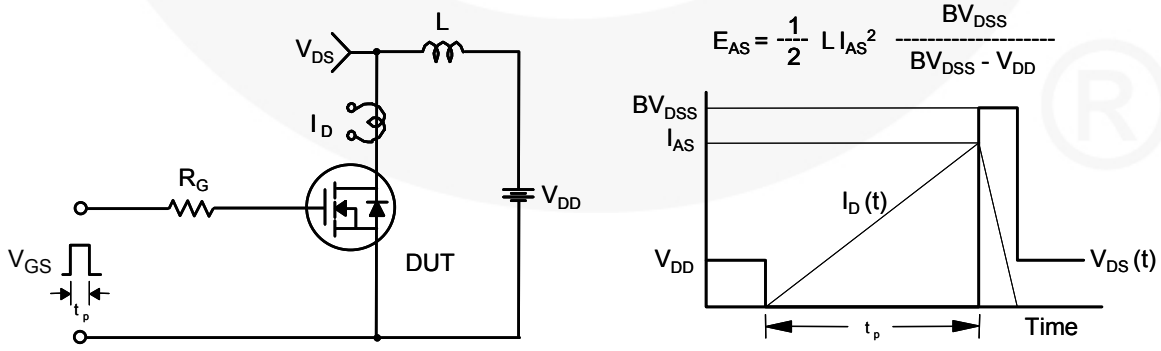
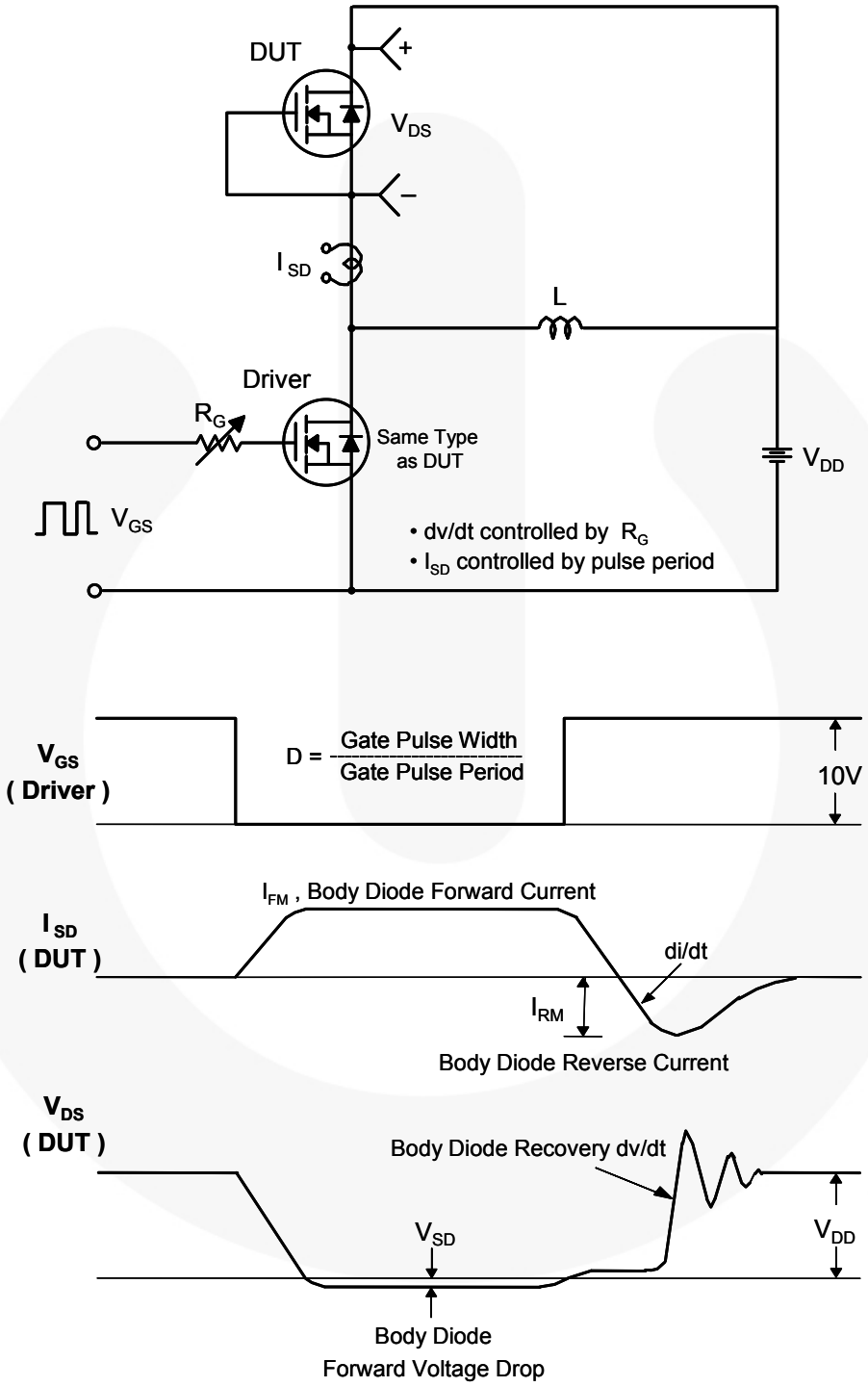


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



Mechanical Dimensions

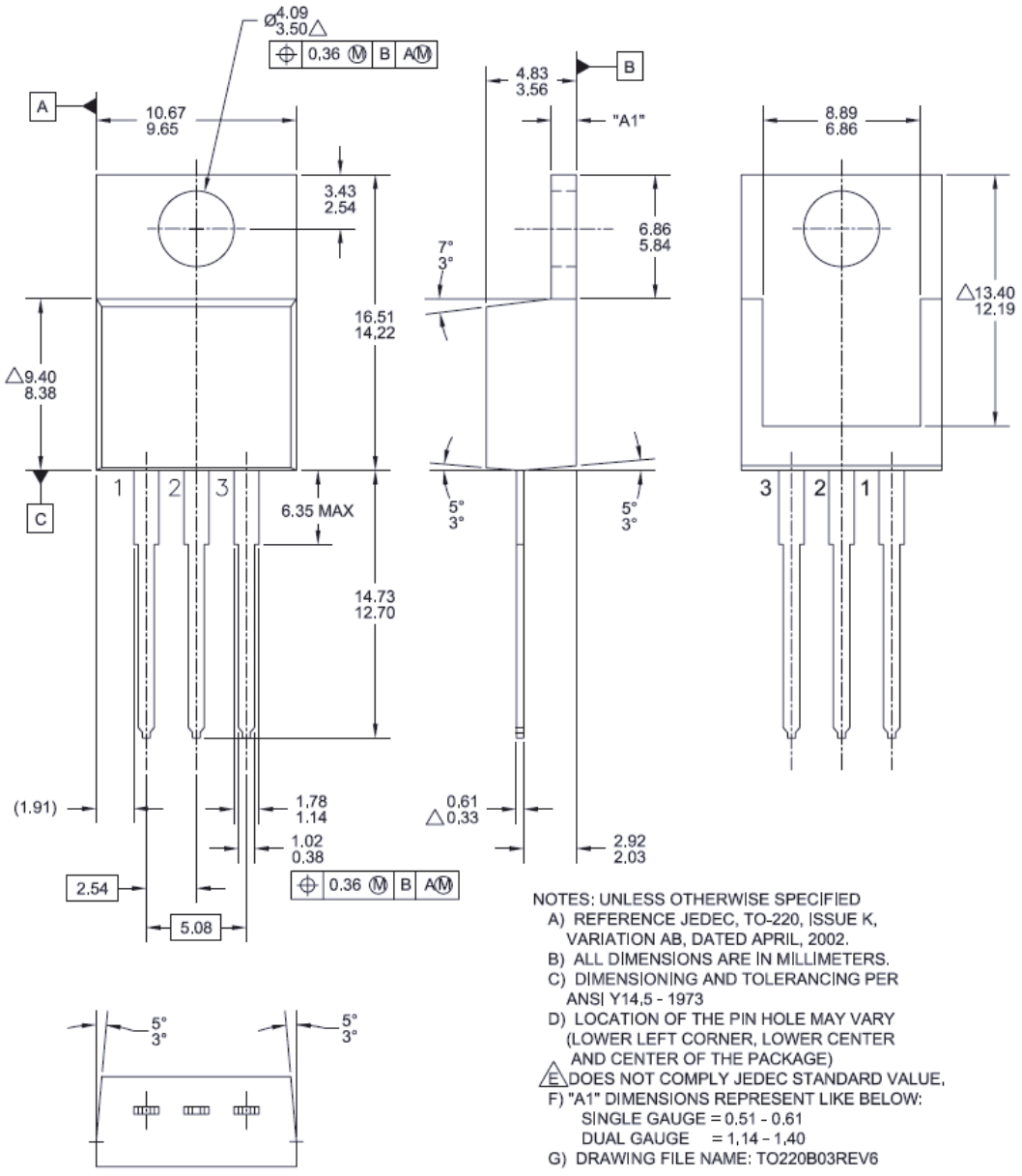


Figure 16. TO-220, Molded, 3-Lead, Jedec Variation AB

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Rev. I66

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Телефон: +7 812 627 14 35

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Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
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